TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG34AFS

Non-Inverter

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

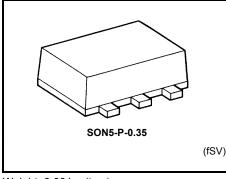
at $V_{CC} = 3.0 \text{ V}$

• High-speed operation: t_{pd} = 2.3 ns (typ.)

at V_{CC} = 3.3 V,15pF

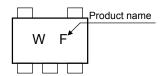
Operating voltage range: V_{CC} = 0.9~3.6 V

• 5.5-V tolerant input.

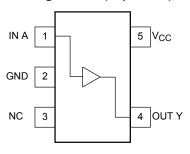


Weight: 0.001 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~ V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20 (Note 1)	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	50	mW
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

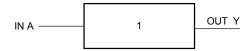
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Vout < GND, Vout > Vcc

Truth Table

A Y L L H H

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	0.9~3.6	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	٧
Output Current		±8.0 (Note 2)	
	I _{OH} /I _{OL}	±4.0 (Note 3)	
		±3.0 (Note 4)	mA
		±1.7 (Note 5)	IIIA
		±0.3 (Note 6)	
		±0.02 (Note 7)	
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dV	0~10 (Note 8)	ns/V

Note 2: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 3: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 4: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 5: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 6: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 7: $V_{CC} = 0.9 V$

Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

DC Electrical Characteristics

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
		rest	V _{CC} (V		Min	Тур.	Max	Min	Max	Unit
High-level VIH input voltage				0.9	Vcc		_	Vcc	_	
		_		1.1~1.3	V _{CC} × 0.7		_	V _{CC} × 0.7		V
	V _{IH}			1.4~1.6	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_	
				1.65~ 1.95	V _{CC} × 0.65	_	_	V _{CC} × 0.65	_	
				2.3~2.7	1.7	_	_	1.7	_	
				3.0~3.6	2.0	_	_	2.0	_	
				0.9	_	_	GND	_	GND	
Low-level V _{IL} input voltage				1.1~1.3	_		V _{CC} × 0.3	_	V _{CC} × 0.3	
		_		_		V _{CC} × 0.35	_	V _{CC} × 0.35	V	
				_		V _{CC} × 0.35	_	V _{CC} × 0.35		
				_	_	0.7	_	0.7		
				3.0~3.6	_		8.0		0.8	
High-level V _{OH} output voltage	Voн	$V_{IN} = V_{IH}$	$I_{OH} = -0.02 \text{ mA}$	0.9	0.75	_		0.75	_	· · · · · · · · · · · · · · · · · · ·
			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
			$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75		_	V _{CC} × 0.75		
			$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45		
			I _{OH} = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48	_	
Low-level output voltage			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1		0.1	V
			$I_{OL} = 0.3 \text{ mA}$	1.1~1.3	_		V _{CC} × 0.25	_	V _{CC} × 0.25	
	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25	_	V _{CC} × 0.25	
			I _{OL} = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	
			I _{OL} = 4.0 mA	2.3~2.7	_		0.4	_	0.4	
			I _{OL} = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4	
Input leakage current	I _{IN}	V _{IN} = 0~5.5V		0~3.6	_		±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		3.6	_	_	1.0	_	10.0	μА

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns,}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
		C_L = 10 pF, R_L = 1 M Ω	0.9	_	18.6	_	_	_	
			1.1~1.3	_	8.7	18.4	1.0	34.2	
			1.4~1.6	_	4.9	8.5	1.0	10.0	
			1.65~ 1.95	_	3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
		C_L = 15 pF, R_L = 1 M Ω	0.9	_	21.0	_	_	_	
	tpLH tpHL		1.1~1.3	_	9.8	21.5	1.0	37.1	ns
			1.4~1.6	_	5.4	9.3	1.0	11.2	
Propagation delay time			1.65~ 1.95	_	4.2	6.9	1.0	7.1	
			2.3~2.7	_	2.8	4.4	1.0	5.0	
			3.0~3.6	_	2.3	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	31.2	_	_	_	
			1.1~1.3	_	13.8	29.6	1.0	56.0	
			1.4~1.6	_	7.4	13.1	1.0	15.9	
			1.65~ 1.95	_	5.6	9.2	1.0	9.6	
			2.3~2.7	_	3.7	5.7	1.0	6.1	
			3.0~3.6	_	2.9	4.4	1.0	4.8	
Input capacitance	C _{IN}	_	3.6	_	3	_		_	pF
Power dissipation capacitance	C _{PD}	(Note9)	0.9~3.6	_	6	_	_	_	pF

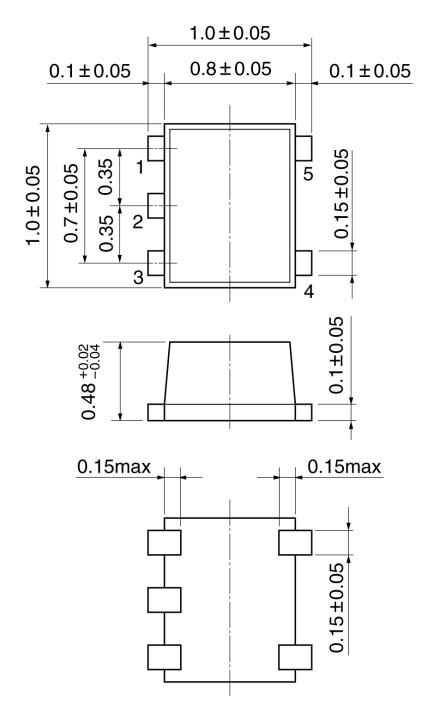
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SON5-P-0.35 Unit:mm



Weight: 0.001 g (typ.)

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20070701-EN GENERAL

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